NSN 5961-01-226-2100

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Inclosure Material:

Metal

Overall Length:

0.060 inches

Terminal Length:

0.250 inches

Overall Diameter:

0.215 inches

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-50

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-emitter, base open and 20.0 breakdown voltage, collector-to-base, emitter open

Current Rating Per Characteristic:

20.00 amperes source cutoff current

Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector

Transfer Ratio:

30.0 static forward current transfer ratio, common-emitter and 120.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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